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Vishay Semiconductors

AUTOMOTIVE

COMPLIANT HALOGEN

FREE

# Hyperfast Rectifier, 2 A FRED Pt®

## eSMP® Series



**Top View** 

**Bottom View** 

#### SlimSMAW (DO-221AD)



### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 A			
$V_{R}$	100 V, 200 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>FSM</sub>	60 A			
t <sub>rr</sub> (typ.)	15 ns			
T <sub>J</sub> max.	175 °C			
Package	SlimSMAW (DO-221AD)			
Circuit configuration	Single			

#### **FEATURES**

- Low profile package
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

## **DESCRIPTION / APPLICATIONS**

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

### **MECHANICAL DATA**

Case: SlimSMAW (DO-221AD)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse	VS-2EYH01HM3	V		100	V	
voltage	VS-2EYH02HM3	- V <sub>RRM</sub>		200	V	
Average rectified forward current		I <sub>F(AV)</sub> (1)	T <sub>C</sub> = 151 °C	2	А	
Non-repetitive peak surge current		I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 10 ms sine pulse wave	60		
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	

#### Note

(1) Mounted on infinite heatsink

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking _voltage	VS-2EYH01HM3	$V_{BR}$ , $V_{R}$	Ι <sub>R</sub> = 100 μΑ	100	-	-	V
	VS-2EYH02HM3			200	-	-	
Converd valtage per diade		V <sub>F</sub>	I <sub>F</sub> = 2 A	-	0.86	0.93	
Forward voltage, per diode	I <sub>F</sub> = 2 A, T <sub>J</sub> = 150 °C		-	0.69	0.75		
Reverse leakage current, per diode		I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	2	μА
			$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	ı	20	
Junction capacitance		C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF

# VS-2EYH01HM3, VS-2EYH02HM3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNITS
Reverse recovery time		$I_F = 1.0 \text{ A, dI}_F/\text{dt} =$	= 50 A/μs, V <sub>R</sub> = 30 V	-	22	-	
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	: 100 A/μs, V <sub>R</sub> = 30 V	-	15	-	
	t <sub>rr</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1A, I <sub>rr</sub> = 0.25 A		-	-	28	ns
		T <sub>J</sub> = 25 °C	$I_F = 2 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 100 \text{ V}$	-	16	-	Δ.
		T <sub>J</sub> = 125 °C		-	26	-	
Peak recovery current		T <sub>J</sub> = 25 °C		-	2.7	-	
	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	3.4	-	A
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	20	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	43	-	I IIC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount		R <sub>thJM</sub> (1)	Infinite heatsink	-	12	15	
Thermal resistance, junction to ambient		R <sub>thJA</sub>	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W
VS-2EYH01HM3			Case style SlimSMAW (DO-221AD)	2H1			
Marking device	VS-2EYH02HM3		Case style Sill ISWAW (DO-22 IAD)		2H2		

#### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

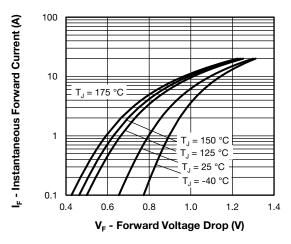


Fig. 1 - Typical Forward Voltage Drop Characteristics

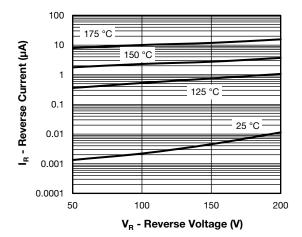


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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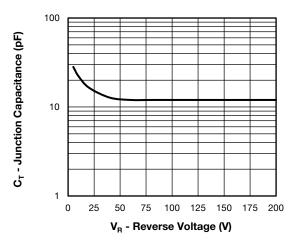


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

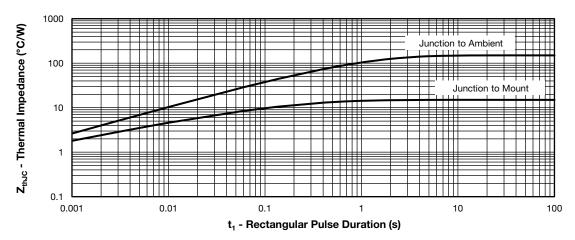


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

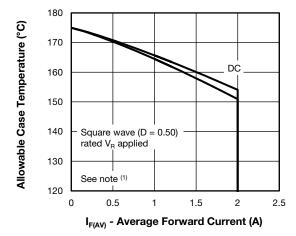


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

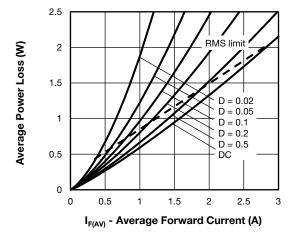


Fig. 6 - Forward Power Loss Characteristics

### Note

<sup>&</sup>lt;sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 5);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = rated V_R$ 

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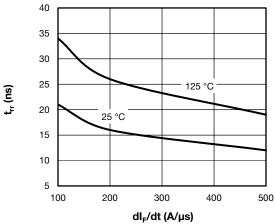


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

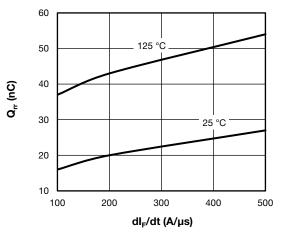
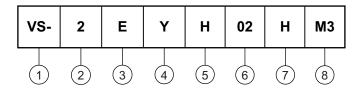


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (2 = 2 A)
- 3 Circuit configuration:
  - E = single diode
- Y = SlimSMAW (DO-221AD)
- 5 Process type,
  - H = hyperfast recovery
- 6 Voltage code (02 = 200 V)
- 7 H = AEC-Q101 qualified
- 8 M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-2EYH01HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH01HM3/I	0.033	1	14 000	13"diameter plastic tape and reel			
VS-2EYH02HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH02HM3/I	0.033	1	14 000	13"diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96582</u>					
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96585				



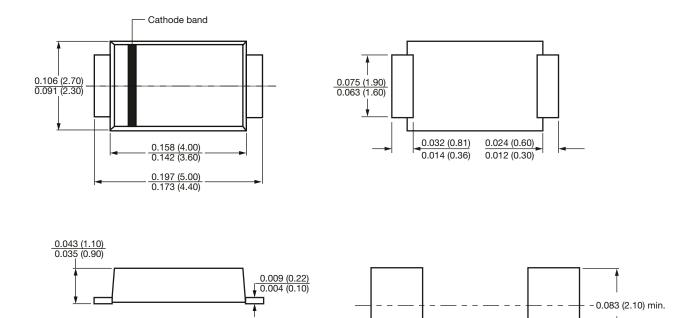
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0.055 (1.40) min.

# SlimSMAW (DO-221AD)

## **DIMENSIONS** in inches (millimeters)

## SlimSMAW (DO-221AD)



0.055 (1.40) min.

Mounting pad layout

0.118 (3.00) max.

0.228 (5.80) ref.



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